



#### **NSBA114EF3T5G Information**



For Reference Only

Part Number NSBA114EF3T5G Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single, Pre-Biased

**Description** TRANS PREBIAS PNP 254MW SOT1123

Package SOT-1123

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









## **NSBA114EF3T5G Specifications**

	Report errors?
Supplier Device Package	SOT-1123
Package / Case	SOT-1123
Mounting Type	Surface Mount
Power - Max	254mW
Frequency - Transition	-
Current - Collector Cutoff (Max)	500nA
Vce Saturation (Max) @ Ib, Ic	250mV @ 300μA, 10mA
DC Current Gain (hFE) (Min) @ Ic, Vce	35 @ 5mA, 10V
Resistor - Emitter Base (R2) (Ohms)	10k
Resistor - Base (R1) (Ohms)	10k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	100mA
Transistor Type	PNP - Pre-Biased
Series	-
Package	SOT-1123
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Category	Discrete Semiconductor Products
Manufacturer	ON Semiconductor
Manufacturer Part Number	NSBA114EF3T5G

#### **NSBA114EF3T5G Guarantees**



#### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

# **NSBA114EF3T5G Payment Methods**





















### **NSBA114EF3T5G Shipping Methods**













If you have any question about NSBA114EF3T5G, please do not hesitate to contact us!

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